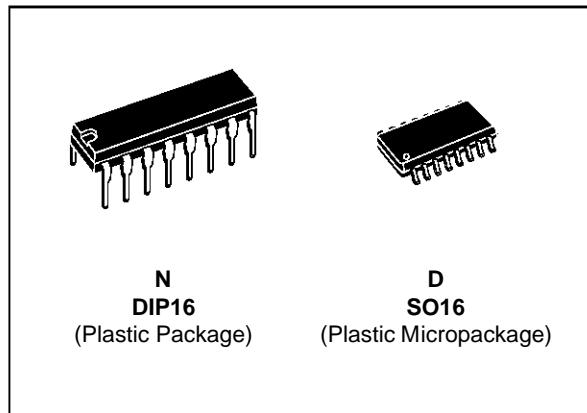


INPUT/OUTPUT RAIL TO RAIL QUAD CMOS OPERATIONAL AMPLIFIER (WITH STANDBY POSITION)

- RAIL TO RAIL INPUT AND OUTPUT VOLTAGE RANGES
 - 2 SEPARATE STANDBY : REDUCED CONSUMPTION AND HIGH IMPEDANCE OUTPUTS
 - SINGLE (OR DUAL) SUPPLY OPERATION FROM 2.7V TO 16V ($\pm 1.35V$ to $\pm 8V$)
 - EXTREMELY LOW INPUT BIAS CURRENT : 1pA TYP
 - LOW INPUT OFFSET VOLTAGE : 5mV max.
 - SPECIFIED FOR 600 Ω AND 150 Ω LOADS
 - LOW SUPPLY CURRENT : 400 μA /Ampli
($V_{CC} = 10V$)



ORDER CODES

Part Number	Temperature Range	Package	
		N	D
TS904I/AI	-40, +125°C	•	•

DESCRIPTION

The TS904 is a RAIL TO RAIL quad CMOS operational amplifier designed to operate with single or dual supply voltage.

The input voltage range V_{icm} includes the two supply rails V_{CC^+} and V_{CC^-} .

The output reaches :

- $V_{CC^-} + 50mV \quad V_{CC^+} - 50mV$ with $R_L = 10k\Omega$
 - $V_{CC^-} + 650mV \quad V_{CC^+} - 650mV$ with $R_L = 600\Omega$

This product offers a broad supply voltage operating range from 2.7V to 16V and a supply current of only 400 μ A/amp. ($V_{CC} = 10V$)

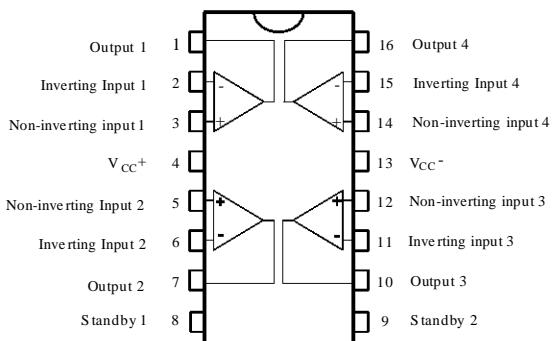
Source and sink output current capability is typically 60mA (at $V_{CC} = 10V$), fixed by an internal limitation circuit.

The TS904 offers two separate **STANDBY** pins:

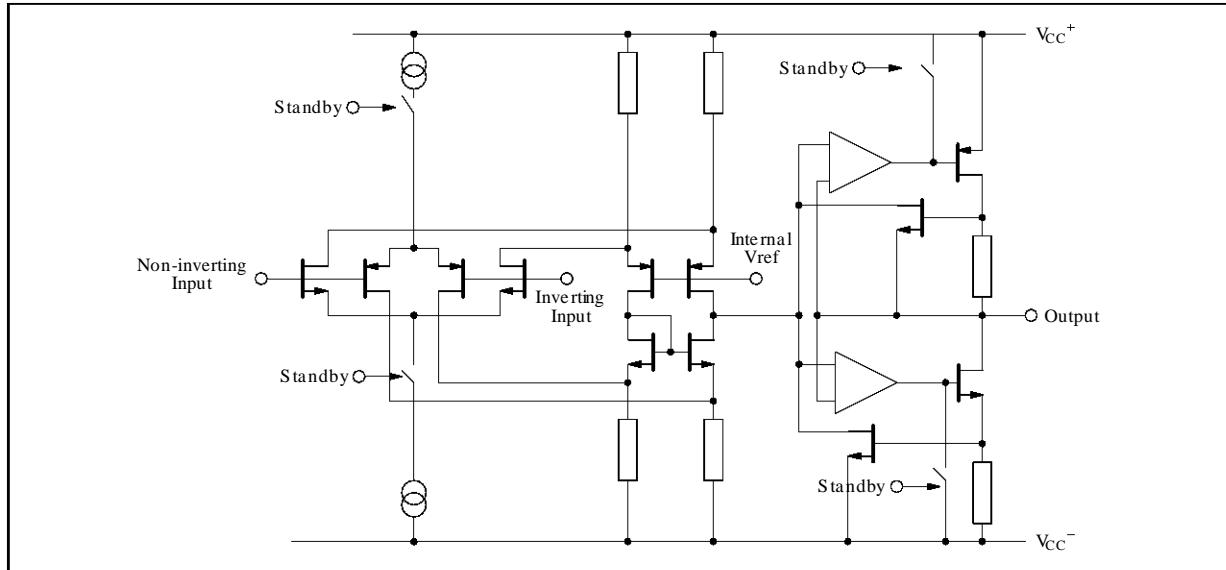
- STANDBY 1 acting on the n°2 and n°3 operators
 - STANDBY 2 acting on the n°1 and n°4 operators

They reduce the consumption of the corresponding operators and put the outputs in a high impedance state.

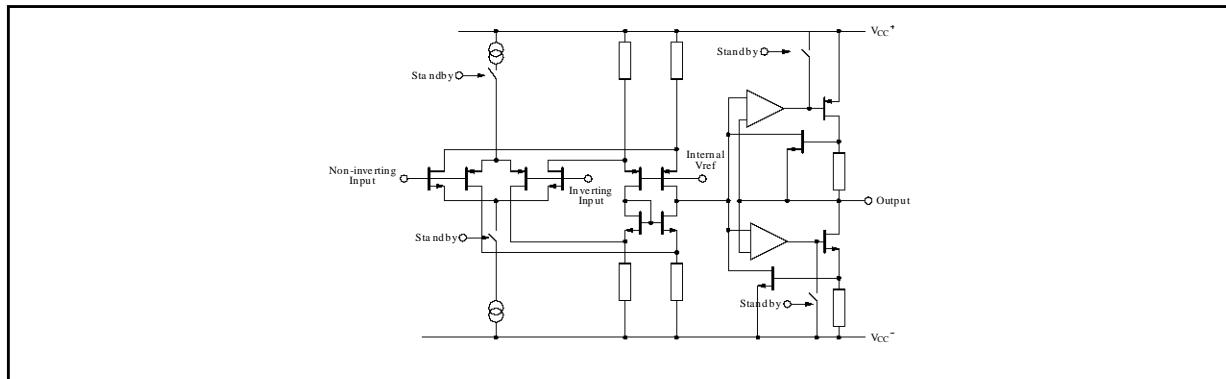
These two STANDBY pins should never stay not connected.



SCHEMATIC DIAGRAM (1/4 TS904)



STANDBY POSITION



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage - (note 1)	18	V
V_{id}	Differential Input Voltage - (note 2)	± 18	V
V_i	Input Voltage - (note 3)	-0.3 to 18	V
I_{in}	Current on Inputs	± 50	mA
I_o	Current on Outputs	± 130	mA
T_{oper}	Operating Free Air Temperature Range TS904I/AI	-40 to +125	°C
T_{stg}	Storage Temperature	-65 to +150	°C

Notes :

1. All voltage values, except differential voltage are with respect to network ground terminal.
2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
3. The magnitude of input and output voltages must never exceed $V_{CC}^+ + 0.3V$.

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	2.7 to 16	V
V_{icm}	Common Mode Input Voltage Range	$V_{CC}^- - 0.2$ to $V_{CC}^+ + 0.2$	V

ELECTRICAL CHARACTERISTICS

$V_{CC}^+ = 10V$, $V_{CC}^- = 0V$, R_L, C_L connected to $V_{CC}/2$, pin 8 and 9 connected to V_{CC}^+ , $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter		Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ($V_{ic} = V_o = V_{CC}/2$) $T_{min.} \leq T_{amb} \leq T_{max.}$	TS904 TS904A TS904 TS904A			10 5 12 7	mV
DV_{io}	Input Offset Voltage Drift			5		$\mu V/\text{ }^\circ\text{C}$
I_{io}	Input Offset Current - (note 1) $T_{min.} \leq T_{amb} \leq T_{max.}$			1	100 200	pA
I_{ib}	Input Bias Current - (note 1) $T_{min.} \leq T_{amb} \leq T_{max.}$			1	150 300	pA
I_{cc}	Supply Current (per amplifier, $A_{VCL} = 1$, no load) $T_{min.} \leq T_{amb} \leq T_{max.}$			400	600 700	μA
CMR	Common Mode Rejection Ratio $V_{ic} = 3 \text{ to } 7V, V_o = 5V$ $V_{ic} = 0 \text{ to } 10V, V_o = 5V$		50	75 70		dB
SVR	Supply Voltage Rejection Ratio ($V_{CC}^+ = 5 \text{ to } 10V, V_o = V_{CC}/2$)		50	80		dB
A_{vd}	Large Signal Voltage Gain ($R_L = 10k\Omega, V_o = 2.5V \text{ to } 7.5V$) $T_{min.} \leq T_{amb} \leq T_{max.}$		20 15	60		V/mV
V_{OH}	High Level Output Voltage ($V_{id} = 1V$) $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$ $T_{min.} \leq T_{amb} \leq T_{max.}$		9.85 9.2 9.8 9	9.95 9.35 7.8		V
V_{OL}	Low Level Output Voltage ($V_{id} = -1V$) $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$ $T_{min.} \leq T_{amb} \leq T_{max.}$			50 650 2300	150 800 150 900	mV
I_o	Output Short Circuit Current ($V_{id} = \pm 1V$) Source ($V_o = V_{CC}^-$) Sink ($V_o = V_{CC}^+$)		45 45	60 60		mA
GBP	Gain Bandwidth Product ($A_{VCL} = 100, R_L = 10k\Omega, C_L = 100pF, f = 100kHz$)				1.3	MHz
SR ⁺	Positive Slew Rate ($A_{VCL} = 1, R_L = 10k\Omega, C_L = 100pF, V_i = 2.5V \text{ to } 7.5V$)				1.3	$V/\mu s$
SR ⁻	Negative Slew Rate ($A_{VCL} = 1, R_L = 10k\Omega, C_L = 100pF, V_i = 2.5V \text{ to } 7.5V$)				0.8	$V/\mu s$
\emptyset_m	Phase Margin				40	Degrees
e_n	Equivalent Input Noise Voltage ($R_s = 100\Omega, f = 1kHz$)				30	$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion ($A_{VCL} = 1, R_L = 10k\Omega, C_L = 100pF, V_o = 4.75V \text{ to } 5.25V, f = 1kHz$)				0.024	%
C_{in}	Input Capacitance				1.5	pF
V_{O1}/V_{O2}	Channel Separation ($f = 1kHz$)				120	dB

Note 1 : Maximum values including unavoidable inaccuracies of the industrial test.

STANDBY MODE

$V_{CC}^+ = 10V, V_{CC}^- = 0V, T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	TS904I/AI			Unit
		Min.	Typ.	Max.	
$V_{in\ SBY/ON}$	Pin 8/9 Threshold Voltage for STANDBY ON			8.2	V
$V_{in\ SBY/OFF}$	Pin 8/9 Threshold Voltage for STANDBY OFF			8.5	V
$I_{CC\ SBY}$	Total Consumption Standby 1 ON - Standby 2 OFF Standby 1 OFF - Standby 2 ON Standby 1 and 2 ON			800 800 2	μA

TYPICAL CHARACTERISTICS

(standby OFF = standby 1 and 2 OFF)
(standby ON = standby 1 and 2 ON)

Figure 1a : Supply Current (each amplifier) versus Supply Voltage

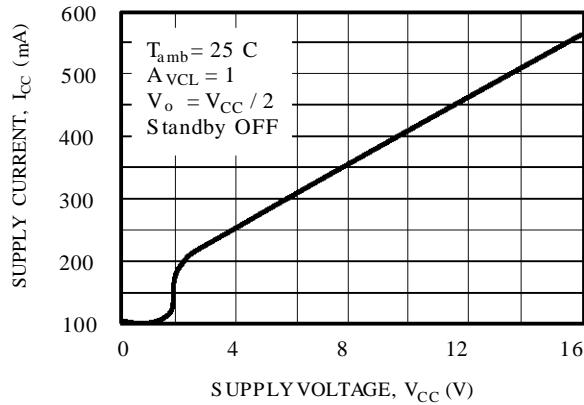


Figure 1b : Supply Current (each amplifier) versus Supply Voltage (in STANDBY)

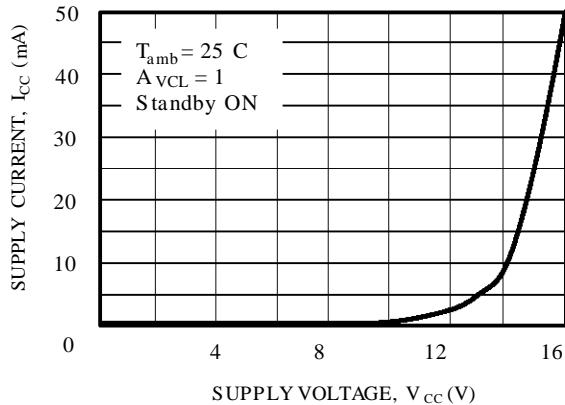


Figure 2 : Input Bias Current versus Temperature

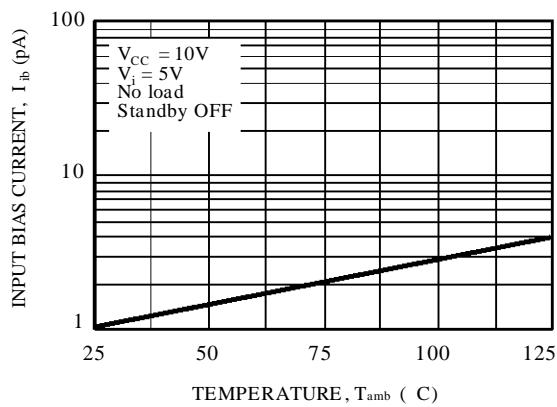


Figure 3a : High Level Output Voltage versus High Level Output Current

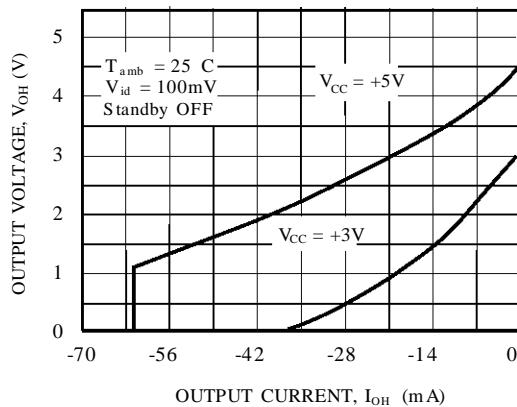


Figure 3b : High Level Output Voltage versus High Level Output Current

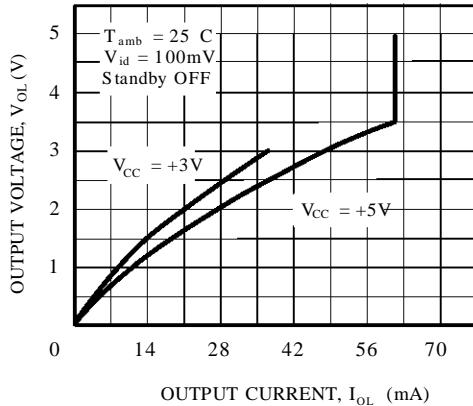


Figure 4a : Low Level Output Voltage versus Low Level Output Current

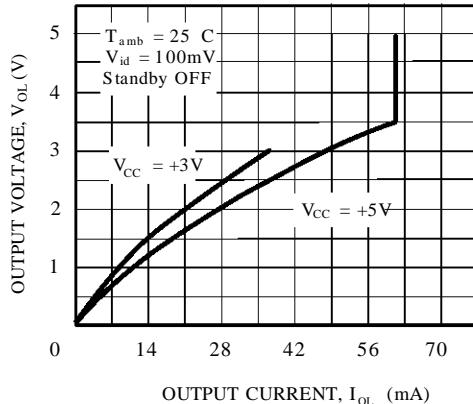


Figure 4b : Low Level Output Voltage versus Low Level Output Current

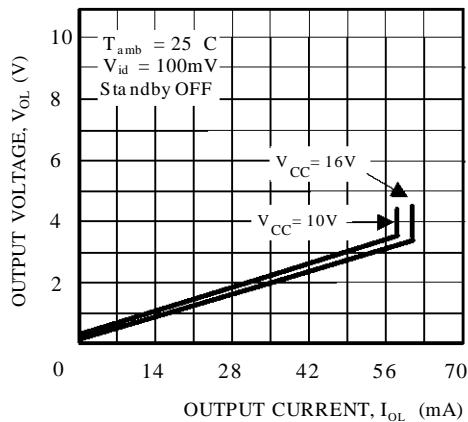


Figure 5b : Open Loop Frequency Response and Phase Shift

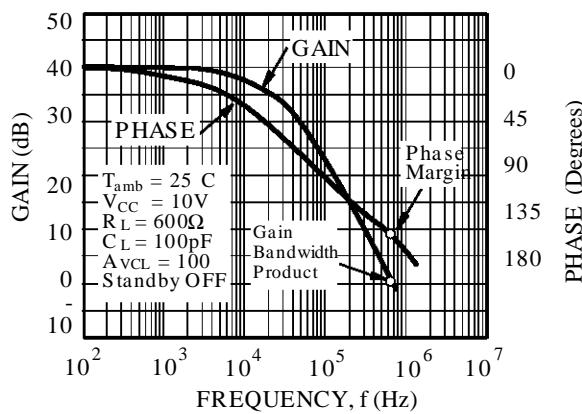


Figure 6b : Gain bandwidth Product versus Supply Voltage

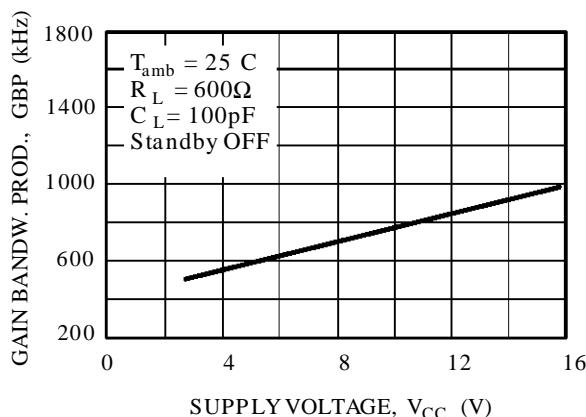


Figure 5a : Open Loop Frequency Response and Phase Shift

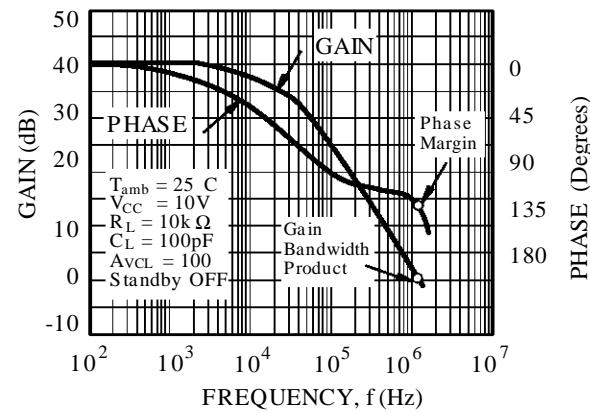


Figure 6a : Gain Bandwidth Product versus Supply Voltage

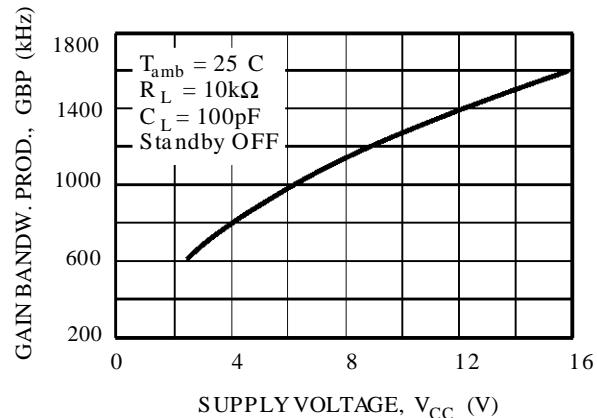


Figure 7a : Phase Margin versus Supply Voltage

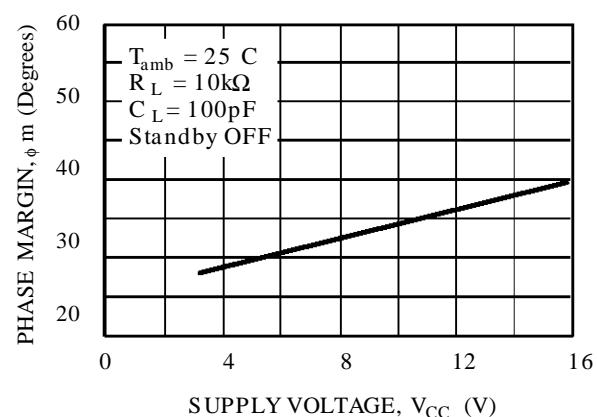
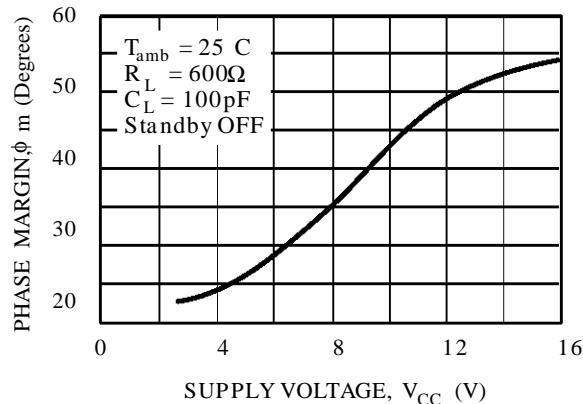
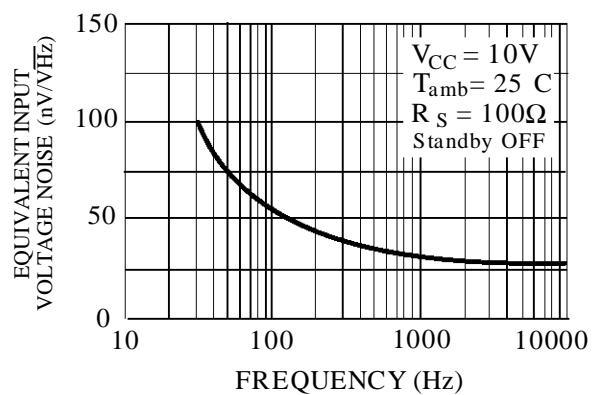


Figure 7b : Phase Margin versus Supply Voltage**Figure 8 : Input Voltage Noise versus Frequency**

STANDBY APPLICATION

The TS904 offers two separate STANDBY pins :

- **STANDBY 1** (pin 8) acting on the n°2 and n°3 operators.
- **STANDBY 2** (pin 9) acting on the n°1 and n°4 operators.

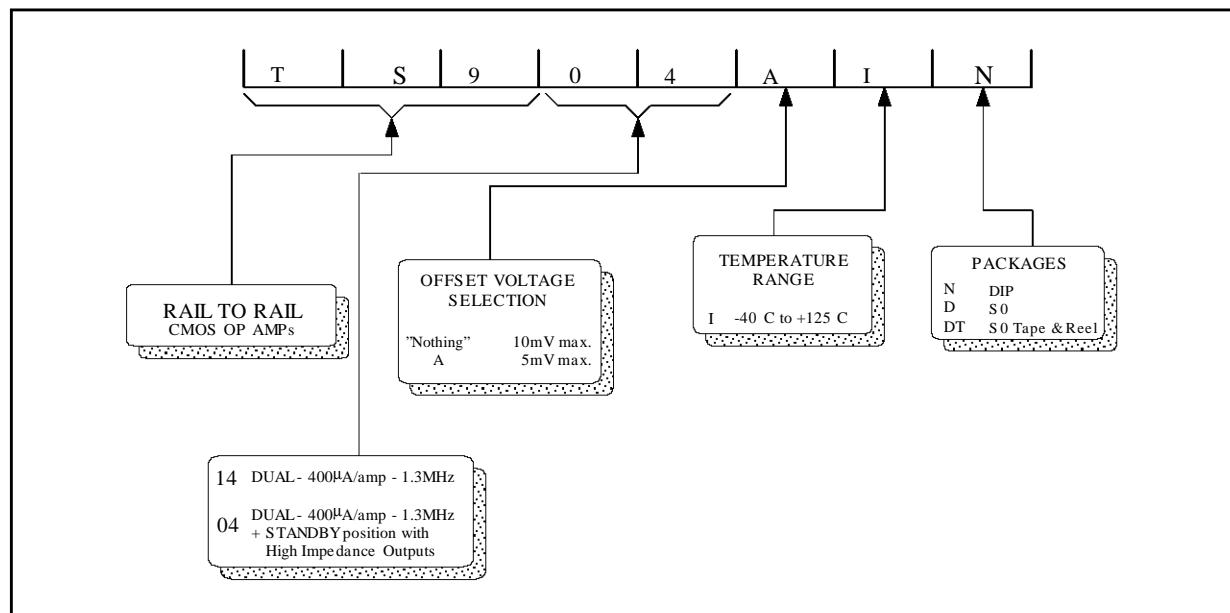
When one of these standby is activated (STANDBY ON) :

- The supply current of the corresponding operators is considerably reduced. The total consumption of the circuit is then divided by 2 (one STANDBY ON) or decreased down to 0.5µA ($V_{CC} = 3V$, two STANDBY ON). (ref. figure 1b).
- All the outputs of the corresponding operators are in high impedance state. No output current can then be sourced or sunked.

The standby pins 8 and 9 should never stay unconnected.

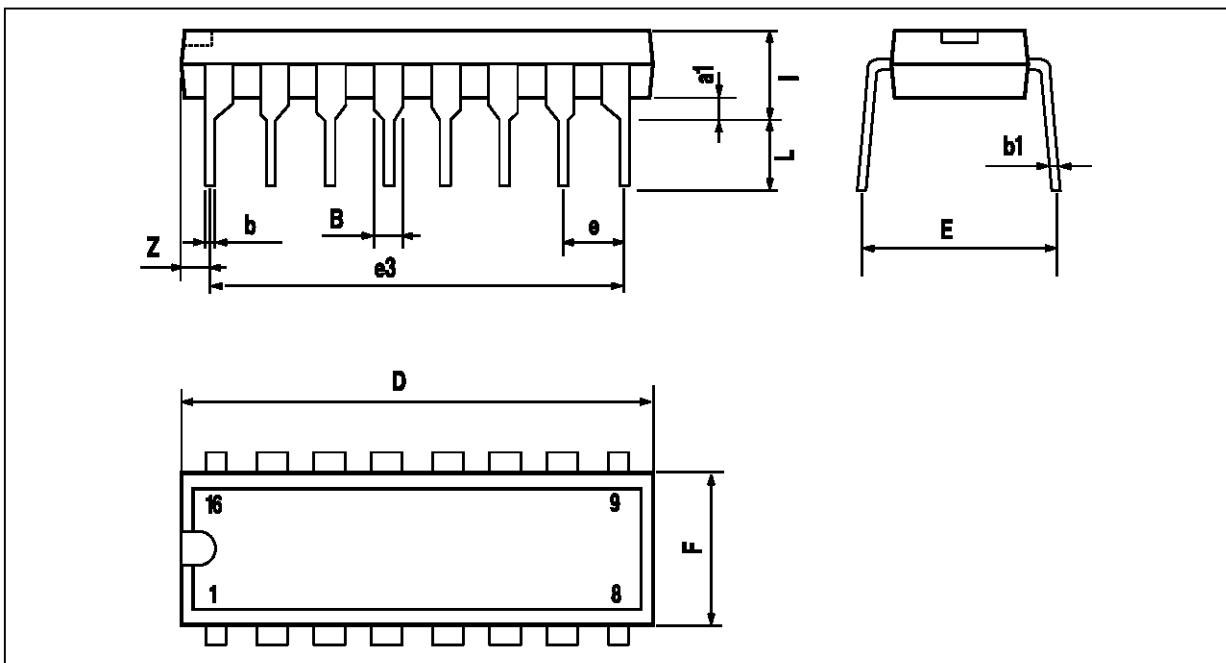
- The "standby OFF" state, is reached when the pins 8 or 9 voltage is **higher than $V_{in\ SBY/OFF}$** .
- The "standby ON" state, is assured by the pins 8 or 9 voltage **lower than $V_{in\ SBY/OFF}$** .
(see electrical characteristics)

ORDERING INFORMATION



PACKAGE MECHANICAL DATA

16 PINS - PLASTIC DIP

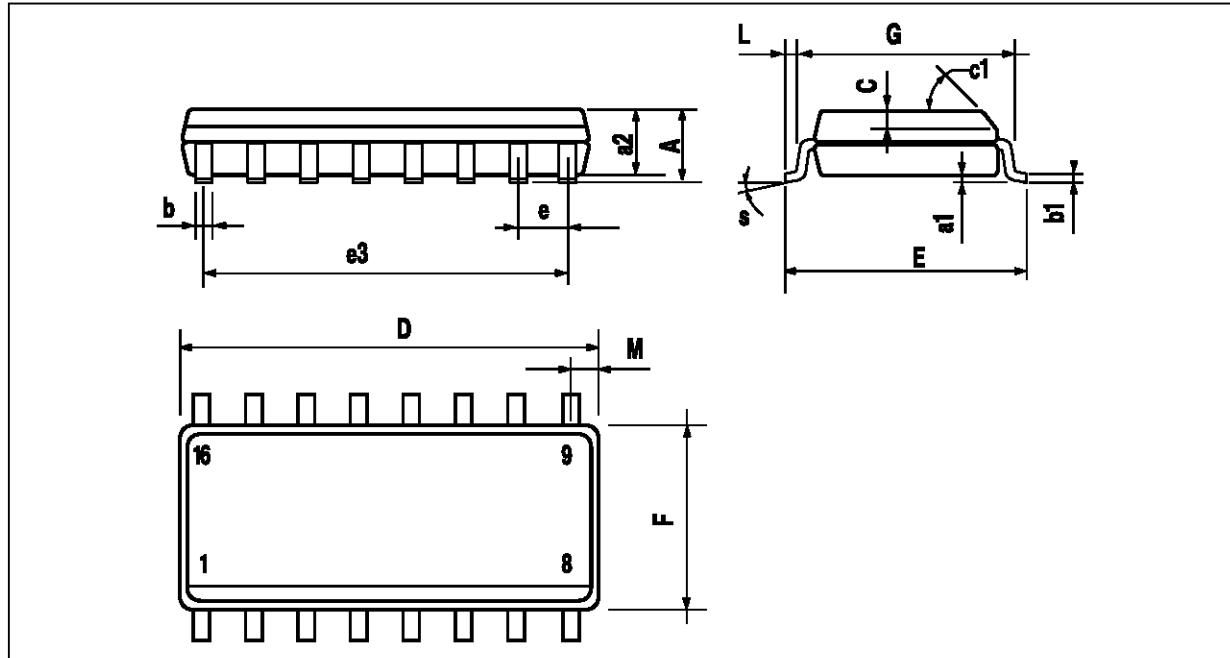


PM-DIP16.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050

DIP16.TBL

PACKAGE MECHANICAL DATA
16 PINS - PLASTIC MICROPACKAGE (SO)



PM-SO16.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D	9.8		10	0.386		0.394
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.209
L	0.5		1.27	0.020		0.050
M			0.62			0.024
S	8° (max.)					

SO16.TBL

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